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**April 2016** 

# FODM100x Series Single Channel, DC Sensing Input, Phototransistor Optocoupler In Stretched Body SOP 4-Pin

#### **Features**

- ≥ 8 mm Creepage and Clearance Distance, and ≥ 0.4 mm Insulation Distance to Achieve Reliable and High Voltage Insulation
- · Safety and Regulatory Approvals
- UL1577, 5,000 VAC<sub>RMS</sub> for 1 min.
- DIN\_EN/IEC60747-5-5, 890 V\_Peak Working Voltage (pending approval)
- High Breakdown Collector to Emitter Voltage, BV<sub>CEO</sub> = 70 V minimum
- Extended Industrial Temperate Range, -40 to 110°C
- Current Transfer Ratio at I<sub>F</sub> = 5 mA, V<sub>CE</sub> = 5 V,
   T<sub>A</sub> = 25°C
- FODM1007: 80 to 160%
- FODM1008: 130 to 260%
- FODM1009: 200 to 400%

#### **Related Resources**

- www.fairchildsemi.com/products/optoelectronics/
- www.fairchildsemi.com/datasheets/HM/ HMHA2801.pdf

## Description

The FODM100x Series, single channel, DC sensing input, optocoupler consists of one gallium arsenide (GaAs) infrared light emitting diode optically coupled to one phototransistor, in a stretched body SOP 4-pin package. The input-output isolation voltage,  $V_{\rm ISO}$ , is rated at 5,000 VAC<sub>RMS</sub>.

## **Applications**

- · Primarily suited for DC-DC Converters
- · For ground loop isolation, signal to noise isolation
- Communications adapters, chargers
- · Consumer appliances, set top boxes
- Industrial power supplies, motor control, programmable logic control

## Schematic Package

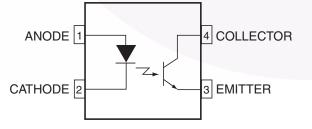


Figure 1. Schematic



Figure 2. Package Outline

## **Safety and Insulation Ratings**

As per DIN EN/IEC 60747-5-5 (pending approval), this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter		Characteristics
Installation Classifications per DIN VDE	< 150 V <sub>RMS</sub>	I–IV
0110/1.89 Table 1, For Rated Mains Voltage	< 300 V <sub>RMS</sub>	I–III
Climatic Classification		40/110/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit		
.,	Input-to-Output Test Voltage, Method A, $V_{IORM}$ x 1.6 = $V_{PR}$ , Type and Sample Test with $t_{m}$ = 10 s, Partial Discharge < 5 pC	1,426	V <sub>peak</sub>		
V <sub>PR</sub>	V <sub>PR</sub> Input-to-Output Test Voltage, Method B, V <sub>IORM</sub> x 1.875 = V <sub>PR</sub> , 100% Production Test with t <sub>m</sub> = 1 s, Partial Discharge < 5 pC				
V <sub>IORM</sub>	Maximum Working Insulation Voltage	890	V <sub>peak</sub>		
$V_{IOTM}$	Highest Allowable Over-Voltage	6,000	V <sub>peak</sub>		
	External Creepage	≥ 8.0	mm		
	External Clearance	≥ 8.0	mm		
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.4	mm		
T <sub>S</sub>	Case Temperature <sup>(1)</sup>	150	°C		
I <sub>S,INPUT</sub>	Input Current <sup>(1)</sup>	200	mA		
P <sub>S,OUTPUT</sub>	Output Power <sup>(1)</sup>	300	mW		
R <sub>IO</sub>	Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub> = 500 V <sup>(1)</sup>	> 10 <sup>9</sup>	Ω		

#### Note:

1. Safety limit values – maximum values allowed in the event of a failure

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. TA = 25°C unless otherwise specified.

Symbol	Parameter	r Value Unit	
TOTAL PACKA	GE	<u> </u>	ı
T <sub>STG</sub>	Storage Temperature	-55 to +150	°C
T <sub>OPR</sub>	Operating Temperature	-40 to +110	°C
T <sub>J</sub>	Junction Temperature	-40 to +125	°C
EMITTER			
I <sub>F (avg)</sub>	Continuous Forward Current	50	mA
I <sub>F (pk)</sub>	Peak Forward Current (1 µs pulse, 300 pps)	1	Α
V <sub>R</sub>	Reverse Input Voltage	6	V
$PD_{LED}$	LED Power Dissipation @ T <sub>A</sub> = 25°C <sup>(2)</sup>	100	mW
, DLED	Derate Above 25°C	0.9	mW/°C
DETECTOR			
I <sub>C</sub>	Continuous Collector Current	50	mA
V <sub>CEO</sub>	Collector-Emitter Voltage	70	V
V <sub>ECO</sub>	Emitter-Collector Voltage	7	V
$PD_{\mathbb{C}}$	Detector Power Dissipation @ T <sub>A</sub> = 25°C (2)	150	mW
. 20	Derate Above 25°C	1.47	mW/°C

#### Note:

2. Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.

## **Electrical Characteristics**

 $T_A = 25$ °C unless otherwise specified.

#### **Individual Component Characteristics**

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit
EMITTER							
V <sub>F</sub>	Forward Voltage	All	I <sub>F</sub> = 50 mA		1.4	1.6	V
I <sub>R</sub>	Reverse Current	All	V <sub>R</sub> = 4 V			10	μA
DETECTO	R						
BV <sub>CEO</sub>	Breakdown Voltage Collector to Emitter	All	I <sub>C</sub> = 1 mA, I <sub>F</sub> = 0	70			V
BV <sub>ECO</sub>	Emitter to Collector	All	$I_E = 0.1 \text{ mA}, I_F = 0$	7			V
I <sub>CEO</sub>	I <sub>CEO</sub> Collector Dark Current		V <sub>CE</sub> = 70 V, I <sub>F</sub> = 0			100	nA
C <sub>CE</sub>	Capacitance	All	V <sub>CE</sub> = 0 V, f = 1 MHz		5		pF

#### **DC Transfer Characteristics**

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit
		FODM1007		80		160	
CTR	DC Current Transfer Ratio	FODM1008	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	130		260	%
		FODM1009		200		400	
V <sub>CE (SAT)</sub>	Saturation Voltage	All	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA			0.3	V

#### **AC Transfer Characteristics**

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit
t <sub>r</sub>	Rise Time (Non-Saturated)	All	$I_C$ = 2 mA, $V_{CE}$ = 5 V, $R_L$ = 100 $\Omega$		5.7	18.0	II C
t <sub>f</sub>	Fall Time (Non-Saturated)	All	$I_C$ = 2 mA, $V_{CE}$ = 5 V, $R_L$ = 100 $\Omega$	$\mathcal{A}$	8.5	18.0	μs

#### **Isolation Characteristics**

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>ISO</sub>	Steady State Isolation Voltage	* ***	$T_A$ = 25 °C, R.H. < 50%, t = 1.0 minute, $I_{I-O} \le 20 \mu A$	5,000			VAC <sub>RMS</sub>

## **Typical Performance Characteristics**

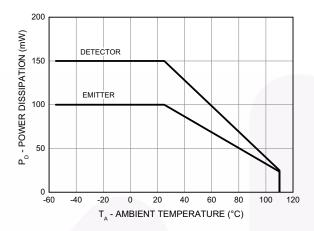


Figure 3. Power Dissipation vs. Ambient Temperature

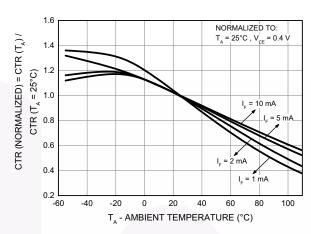


Figure 4. Saturated Normalized Current Transfer Ratio vs. Ambient Temperature

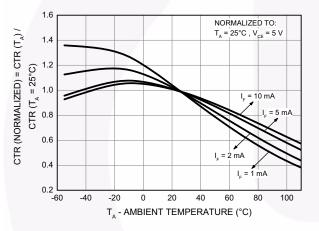


Figure 5. Non-Saturated Normalized Current Transfer Ratio vs. Ambient Temperature

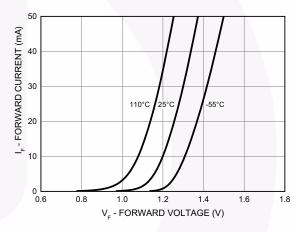


Figure 6. Forward Current vs. Forward Voltage

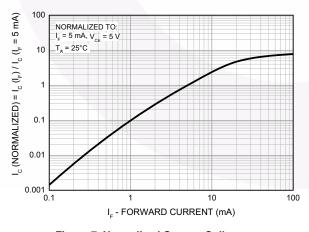


Figure 7. Normalized Current Collector vs. Forward Current

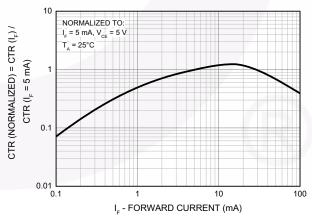
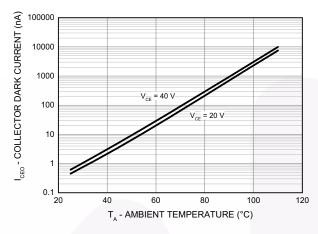


Figure 8. Normalized Current Transfer Ratio vs. Forward Current

## **Typical Performance Characteristics** (Continued)



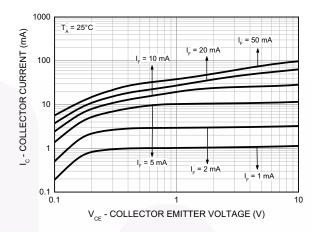
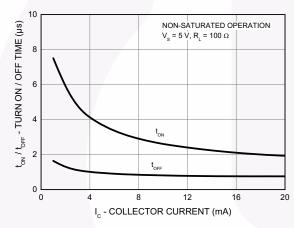


Figure 9. Collector Dark Current vs. Ambient Temperature

Figure 10. Collector Current vs. Collector Emitter Voltage



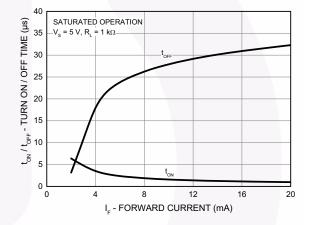
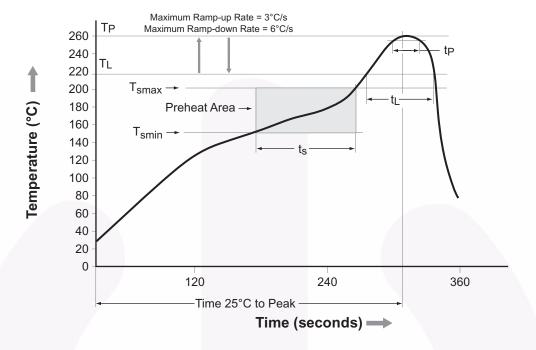


Figure 11. Turn On/Turn Off Time vs. Collector Current

Figure 12. Turn On/ Turn Off Time vs. Forward Current

## **Reflow Profile**



Profile Freature	Pb-Free Assembly Profile		
Temperature Minimum (T <sub>smin</sub> )	150°C		
Temperature Maximum (T <sub>smax</sub> )	200°C		
Time (t <sub>S</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60 s to 120 s		
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second maximum		
Liquidous Temperature (T <sub>L</sub> )	217°C		
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 s to 150 s		
Peak Body Package Temperature	260°C +0°C / –5°C		
Time (t <sub>P</sub> ) within 5°C of 260°C	30 s		
Ramp-Down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/s maximum		
Time 25°C to Peak Temperature	8 minutes maximum		

Figure 13. Reflow Profile

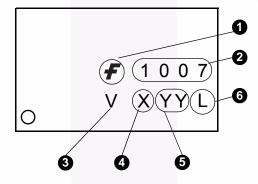
## **Ordering Information**

Part Number	Package	Packing Method
FODM1007	Stretched Body SOP 4-Pin	Tube (100 units per tube)
FODM1007R2	Stretched Body SOP 4-Pin	Tape and Reel (3,000 units per reel)
FODM1007V	Stretched Body SOP 4-Pin,	Tubo (100 unito por tubo)
FODM 1007V	DIN EN/IEC60747-5-5 Option (pending approval)	Tube (100 units per tube)
FODM1007R2V	Stretched Body SOP 4-Pin,	Tape and Reel (3,000 units per reel)
FODIVITION/R2V	DIN EN/IEC60747-5-5 Option (pending approval)	Tape and Neer (3,000 units per reer)

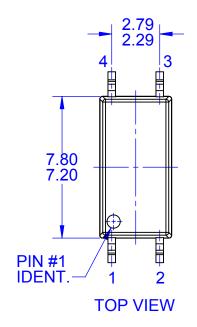
#### Note:

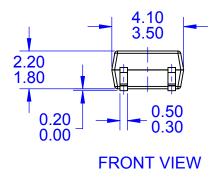
2. The product orderable part number system listed in this table also applies to the FODM1008, and FODM1009 products.

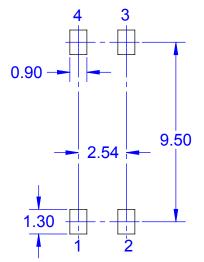
## **Marking Information**



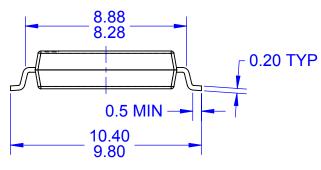
Definiti	Definitions				
1	1 Fairchild Logo				
2	Device Number, e.g. 1007				
3	DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option) (pending for approval)				
4	Last Digit Year Code, e.g. '6'				
5	Two Digit Work Week Ranging from '01' to '53'				
6	Assembly Package Code				







## LAND PATTERN RECOMMENDATION



**SIDE VIEW** 

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- C. DIMENSIONS DO NOT INCLUDE MOLD FLASH **OR BURRS**
- D. DRAWING FILENAME: MKT-LSOP04Arev1







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Definition of Terms		
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Rev. 177

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